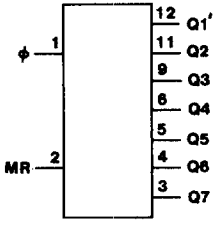
File Number **1683**

CD54/74HC4024
CD54/74HCT4024

High-Speed CMOS Logic



92CS-38450R1

CD54/74HC4024, HCT4024
FUNCTIONAL DIAGRAM

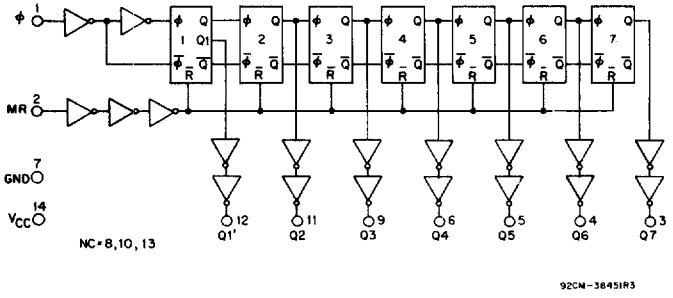
7-Stage Binary Ripple Counter

Type Features:
- *Fully static operation:*
- *Buffered inputs:*
- *Common reset*
- *Typical f_{MAX} = 50 MHz @ V_{CC} = 5 V, C_L = 15 pF, T_A = 25°C*

The RCA-CD54/74HC4024 and CD54/75HCT4024 are 7-stage ripple-carry binary counters. All counter stages are master-slave flip-flops. The state of the stage advances one count on the negative transition of each input pulse; a high voltage level on the MR line resets all counters to their zero state. All inputs and outputs are buffered.

The CD54HC4024 and CD54HCT4024 are supplied in 16-lead hermetic dual-in-line ceramic packages (F suffix). The CD74HC4024 and CD74HCT4024 are supplied in 16-lead dual-in-line plastic packages (E suffix) and in 16-lead dual-in-line surface mount plastic packages (M suffix). Both types are also available in chip form (H suffix).

Family Features:
- *Fanout (over temperature range):*
  Standard outputs - 10 LSTTL loads
  Bus driver outputs - 15 LSTTL loads
- *Wide operating temperature range:*
  CD74HC/HCT: -40 to +85° C
- *Balanced propagation delay and transition times*
- *Significant power reduction compared to LSTTL logic ICs*
- *Alternate source is Philips/Signetics*
- *CD54HC/CD74HC types:*
  2 to 6 V operation
  High noise immunity: N_{IL}= 30%, N_{IH}=30% of V_{CC} @ V_{CC} =5 V
- *CD54HCT/CD74HCT types:*
  4.5 to 5.5 V operation
  Direct LSTTL input logic compatibility
  V_{IL}=0.8 V max., V_{IH}=2 V min.
  CMOS input compatibility
  $I_I \leq 1\ \mu A$ @V_{OL}, V_{OH}



92CM-38451R3

Fig. 1 - Logic diagram for the CD54/74HC/HCT4024.

TRUTH TABLE

ϕ	MR	OUTPUT STATE
⌐	L	No Change
¬	L	Advance to Next State
X	H	All Outputs are Low

H = high level (steady state)
L = low level (steady state)
X = don't care

CD54/74HC4024
CD54/74HCT4024

MAXIMUM RATINGS, *Absolute-Maximum Values:*

DC SUPPLY-VOLTAGE, (V_{CC}):
(Voltages referenced to ground) ..... -0.5 to +7 V
DC INPUT DIODE CURRENT, I_{IK} (FOR $V_I < -0.5$ V OR $V_I > V_{CC}$ +0.5 V) ..... ±20 mA
DC OUTPUT DIODE CURRENT, I_{OK} (FOR $V_o < -0.5$ V OR $V_o > V_{CC}$ +0.5 V) ..... ±20 mA
DC DRAIN CURRENT, PER OUTPUT (I_O) (FOR -0.5 V $< V_o < V_{CC}$ +0.5 V) ..... ±25 mA
DC V_{CC} OR GROUND CURRENT, (I_{CC}) ..... ±50 mA
POWER DISSIPATION PER PACKAGE (P_D):
For T_A = −40 to +60°C (PACKAGE TYPE E) ..... 500 mW
For T_A = +60 to +85°C (PACKAGE TYPE E) ..... Derate Linearly at 8 mW/°C to 300 mW
For T_A = −55 to +100°C (PACKAGE TYPE F, H) ..... 500 mW
For T_A = +100 to +125°C (PACKAGE TYPE F, H) ..... Derate Linearly at 8 mW/°C to 300 mW
For T_A = −40 to +70°C (PACKAGE TYPE M) ..... 400 mW
For T_A = +70 to +125°C (PACKAGE TYPE M) ..... Derate Linearly at 6 mW/°C to 70 mW
OPERATING-TEMPERATURE RANGE (T_A):
PACKAGE TYPE F, H ..... −55 to +125°C
PACKAGE TYPE E, M ..... −40 to +85°C
STORAGE TEMPERATURE (T_{stg}) ..... −65 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 s max. ..... +265°C
Unit inserted into a PC Board (min. thickness 1/16 in., 1.59 mm)
with solder contacting lead tips only ..... +300°C

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range (For T_A=Full Package Temperature Range) V_{CC}:*			
CD54/74HC Types	2	6	V
CD54/74HCT Types	4.5	5.5	
DC Input or Output Voltage, V_I, V_O	0	V_{CC}	V
Operating Temperature, T_A:			
CD74 Types	−40	+85	°C
CD54 Types	−55	+125	
Input Rise and Fall Times, t_r,t_f:			
at 2 V	0	1000	ns
at 4.5 V	0	500	
at 6 V	0	400	

*Unless otherwise specified, all voltages are referenced to Ground.

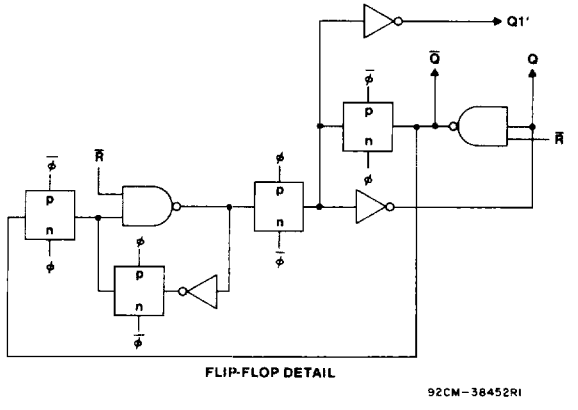


Fig. 2 - Flip-flop No. 1 detail.

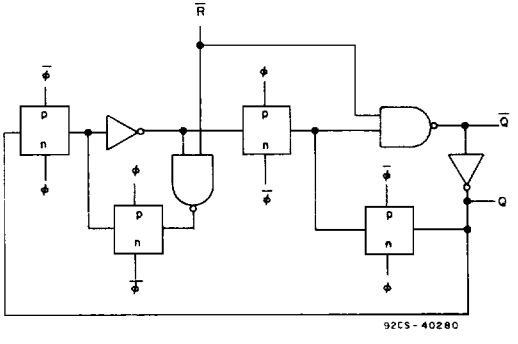


Fig. 3 - Detail for flip-flops 2 through 7.

CD54/74HC4024
CD54/74HCT4024

STATIC ELECTRICAL CHARACTERISTICS

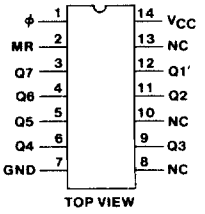
CHARACTERISTICS	CD74HC4024/CD54HC4024										CD74HCT4024/CD54HCT4024									UNITS
	TEST CONDITIONS			74HC/54HC TYPE			74HC TYPE		54HC TYPE		TEST CONDITIONS		74HCT/54HCT TYPE			74HCT TYPE		54HCT TYPE		
				+25°C			-40/ +85°C		-55/ +125°C				+25°C			-40/ +85°C		-55/ +125°C		
	V_I V	I_O mA	V_{CC} V	Min	Typ	Max	Min	Max	Min	Max	V_I V	V_{CC} V	Min	Typ	Max	Min	Max	Min	Max	
High-Level Input Voltage V_{IH}			2	1.5	—	—	1.5	—	1.5	—	—	4.5 to 5.5	2	—	—	2	—	2	—	V
			4.5	3.15	—	—	3.15	—	3.15	—										
			6	4.2	—	—	4.2	—	4.2	—										
Low-Level Input Voltage V_{IL}			2	—	—	0.5	—	0.5	—	0.5	—	4.5 to 5.5	—	—	0.8	—	0.8	—	0.8	V
			4.5	—	—	1.35	—	1.35	—	1.35										
			6	—	—	1.8	—	1.8	—	1.8										
High-Level Output Voltage V_{OH} CMOS Loads	V_{IL} or V_{IH}	-0.02	2	1.9	—	—	1.9	—	1.9	—	V_{IL} or V_{IH}	4.5	4.4	—	—	4.4	—	4.4	—	V
			4.5	4.4	—	—	4.4	—	4.4	—										
			6	5.9	—	—	5.9	—	5.9	—										
TTL Loads	V_{IL} or V_{IH}	-4	4.5	3.98	—	—	3.84	—	3.7	—	V_{IL} or V_{IH}	4.5	3.98	—	—	3.84	—	3.7	—	V
		-5.2	6	5.48	—	—	5.34	—	5.2	—										
Low-Level Output Voltage V_{OL} CMOS Loads	V_{IL} or V_{IH}	0.02	2	—	—	0.1	—	0.1	—	0.1	V_{IL} or V_{IH}	4.5	—	—	0.1	—	0.1	—	0.1	V
			4.5	—	—	0.1	—	0.1	—	0.1										
			6	—	—	0.1	—	0.1	—	0.1										
TTL Loads	V_{IL} or V_{IH}	4	4.5	—	—	0.26	—	0.33	—	0.4	V_{IL} or V_{IH}	4.5	—	—	0.26	—	0.33	—	0.4	V
		5.2	6	—	—	0.26	—	0.33	—	0.4										
Input Leakage Current I_I	V_{CC} or Gnd		6	—	—	±0.1	—	±1	—	±1	Any Voltage Between V_{CC} and Gnd	5.5	—	—	±0.1	—	±1	—	±1	μA
Quiescent Device Current I_{CC}	V_{CC} or Gnd	0	6	—	—	8	—	80	—	160	V_{CC} or Gnd	5.5	—	—	8	—	80	—	160	μA
Additional Quiescent Device Current per Input Pin: 1 Unit Load ΔI_{CC}*											V_{CC} -2.1	4.5 to 5.5	—	100	360	—	450	—	490	μA

*For dual-supply system theoretical worst case (V_I = 2.4 V, V_{CC} = 5.5 V) specification is 1.8 mA.

HCT Input Loading Table

Input	Unit Loads*
ϕ , MR	0.5

*Unit Load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 360 μA max.@25°C.



TOP VIEW

92CS-38453R1

TERMINAL ASSIGNMENT

CD54/74HC4024
CD54/74HCT4024

SWITCHING CHARACTERISTICS (V_{CC}=5 V, T_A=25°C, Input t_r,t_f=6 ns)

CHARACTERISTIC	SYMBOL	C_L (pF)	TYPICAL VALUES HC	TYPICAL VALUES HCT	UNITS
Propagation Delay ϕ to Q1′	t_{PHL} t_{PLH}	15	11	17	ns
Qn to Qn+1	t_{PHL} t_{PLH}	15	6	6	
MR to Q_n	t_{PHL} t_{PLH}	15	14	17	
Power Dissipation Capacitance*	C_{PD}	—	30	30	pF

*C_{PD} is used to determine the dynamic power consumption, per package.

$P_D = C_{PD} V_{CC}^2 fi + \Sigma (C_L V_{CC}^2 fi/M)$ where:

$M = 2^1, 2^2, 2^3, 2^4, 2^5, 2^6, 2^7$

C_L=output load capacitance

fi=input frequency

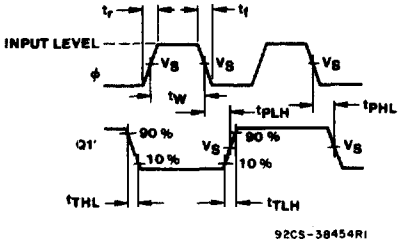
Prerequisite for Switching Function

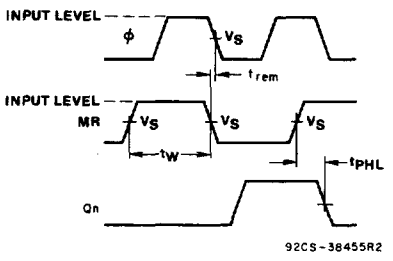
CHARACTERISTIC	SYMBOL	V_{CC}	25°C HC Min.	25°C HC Max.	25°C HCT Min.	25°C HCT Max.	-40°C to +85°C 74HC Min.	-40°C to +85°C 74HC Max.	-40°C to +85°C 74HCT Min.	-40°C to +85°C 74HCT Max.	-55°C to +125°C 54HC Min.	-55°C to +125°C 54HC Max.	-55°C to +125°C 54HCT Min.	-55°C to +125°C 54HCT Max.	UNITS
Maximum Input Pulse Frequency	f_{MAX}	2	6	—	—	—	5	—	—	—	4	—	—	—	MHz
		4.5	30	—	25	—	24	—	20	—	20	—	16	—	
		6	35	—	—	—	29	—	—	—	24	—	—	—	
Input Pulse Width	t_W	2	80	—	—	—	100	—	—	—	120	—	—	—	ns
		4.5	16	—	20	—	20	—	25	—	24	—	30	—	
		6	14	—	—	—	17	—	—	—	20	—	—	—	
Reset Removal Time	t_{REM}	2	50	—	—	—	65	—	—	—	75	—	—	—	
		4.5	10	—	10	—	13	—	13	—	15	—	15	—	
		6	9	—	—	—	11	—	—	—	13	—	—	—	
Reset Pulse Width	t_W	2	80	—	—	—	100	—	—	—	120	—	—	—	
		4.5	16	—	20	—	20	—	25	—	24	—	30	—	
		6	14	—	—	—	17	—	—	—	20	—	—	—	

SWITCHING CHARACTERISTICS (C_L=50 pF, Input t_r,t_f=6 ns)

CHARACTERISTIC	SYMBOL	V_{CC}	25°C HC Min.	25°C HC Max.	25°C HCT Min.	25°C HCT Max.	-40°C to +85°C 74HC Min.	-40°C to +85°C 74HC Max.	-40°C to +85°C 74HCT Min.	-40°C to +85°C 74HCT Max.	-55°C to +125°C 54HC Min.	-55°C to +125°C 54HC Max.	-55°C to +125°C 54HCT Min.	-55°C to +125°C 54HCT Max.	UNITS
Propagation Delay, ϕ to Q1′ Output	t_{PLH}	2	—	140	—	—	—	175	—	—	—	210	—	—	ns
	t_{PHL}	4.5	—	28	—	40	—	35	—	50	—	42	—	60	
		6	—	24	—	—	—	30	—	—	—	36	—	—	
Propagation Delay Qn to Qn+1	t_{PLH}	2	—	75	—	—	—	95	—	—	—	110	—	—	ns
	t_{PHL}	4.5	—	15	—	15	—	19	—	19	—	22	—	22	
		6	—	13	—	—	—	13	—	—	—	19	—	—	
Propagation Delay MR to Q_n	t_{PHL}	2	—	170	—	—	—	215	—	—	—	255	—	—	ns
		4.5	—	34	—	40	—	43	—	50	—	51	—	60	
		6	—	29	—	—	—	27	—	—	—	43	—	—	
Output Transition Time	t_{TLH}	2	—	75	—	—	—	95	—	—	—	110	—	—	ns
	t_{THL}	4.5	—	15	—	15	—	19	—	19	—	22	—	22	
		6	—	13	—	—	—	16	—	—	—	19	—	—	
Input Capacitance	C_I	—	—	10	—	10	—	10	—	10	—	10	—	10	pF

CD54/74HC4024
CD54/74HCT4024





	54/74HC	54/74HCT
Input Level	V_{CC}	3 V
Switching Voltage, V_S	50% V_{CC}	1.3 V

Fig. 4 - Input Pulse pre-requisite times, propagation delays and output transition times.

Fig. 5 - Master Reset pre-requisite and propagation delays.